

80SQ... SERIES

SCHOTTKY RECTIFIER

8 Amp

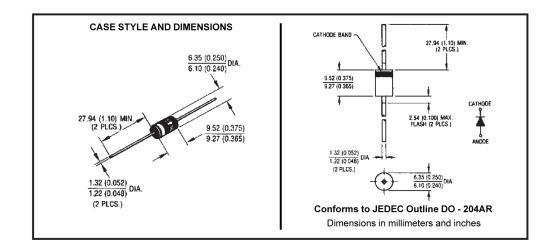
Major Ratings and Characteristics

Cha	racteristics	80SQ	Units
I _{F(AV)}	Rectangular waveform	8	А
V _{RRM}	range	30/45	٧
I _{FSM}	@tp=5µssine	2400	А
V _F	@8Apk, T _J = 125°C	0.44	V
T _J	range	-55 to 175	°C

Description/ Features

The 80SQ axial leaded Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175°C junction temperature. Typical applications are in switching power supplies, converters, free-wheeling diodes, and reverse battery protection.

- 175° C T operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Lead-Free plating



Voltage Ratings

Part number	80SQ030	80SQ035	80SQ040	80SQ045
V _R Max. DC Reverse Voltage (V)		0.5	4.0	45
V _{RWM} Max. Working Peak Reverse Voltage	30	35	40	45

Absolute Maximum Ratings

	Parameters	80SQ	Units	Conditions		
I _{F(AV)}	Max. Average Forward Current *See Fig. 5	8	А	50% duty cycle @ T _C = 119° C, re	ectangular wave form	
I _{FSM}	Max. Peak One Cycle Non-Repetitive	2400	Α	5μs Sine or 3μs Rect. pulse	Following any rated load condition and	
	Surge Current * See Fig. 7	380		10ms Sine or 6ms Rect. pulse	with rated V _{RRM} applied	
E _{AS}	Non-RepetitiveAvalancheEnergy	10	mJ	T _J =25 °C, I _{AS} =1.6 Amps, L=7.8 mH		
I _{AR}	RepetitiveAvalancheCurrent	1.6	Α	Current decaying linearly to zero in 1 µsec		
				Frequency limited by T_J max. $V_A = 1.5 \times V_R$ typical		

Electrical Specifications

	Parameters		Units	Conditions	
V _{FM}	Max. Forward Voltage Drop (1)	0.53	V	@ 8A	T,= 25 °C
	* See Fig. 1	0.60	V	@ 16A	1 _J = 23 C
		0.44	V	@ 8A	T, = 125 °C
		0.55	V	@ 16A	1 123 G
I _{RM}	Max. Reverse Leakage Current (1)	2	mA	T _J = 25 °C	$V_R = \text{rated } V_R$
	* See Fig. 2	15	mA	T _J = 125 °C	V _R = rated V _R
C _T	Max. Junction Capacitance	900	pF	$V_R = 5V_{DC}$, (test signal range 100Khz to 1Mhz) 25 °C	
L _s	Typical Series Inductance	10.0	nΗ	Measured lead to lead 5mm from body	
dv/dt	Max. Voltage Rate of Change (Rated V_R)	10000	V/ µs		

⁽¹⁾ Pulse Width < 300µs, Duty Cycle < 2%

Thermal-Mechanical Specifications

	Parameters	80SQ	Units	Conditions
T _J	Max. Junction Temperature Range	-55 to 175	°C	
T _{stg}	Max. Storage Temperature Range	-55 to 175	°C	
R _{thJL}	Max. Thermal Resistance Junction to Lead	8.0	°C/W	DC operation *See Fig. 4 1/8 inch lead length
R _{thJA}	Typical Thermal Resistance, Junction to Air	44	°C/W	
wt	Approximate Weight	1.4(0.049)	g(oz.)	
	CaseStyle	DO-20	4AR	JEDEC

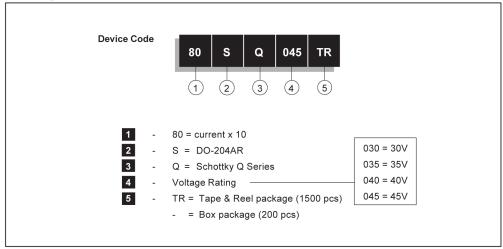
International

TOR Rectifier

80SQ... Series

Bulletin PD-2.047

Ordering Information Table



International

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